NSN 5961-01-277-5134

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-277-5134 **Inclosure Material:** Metal and ceramic **Overall Length:** 1.253 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 6.00 amperes forward current, total rms megahertz and 200.00 microamperes forward current, average outside diameter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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